

MM54C86/MM74C86 Quad 2-Input EXCLUSIVE-OR Gate

General Description

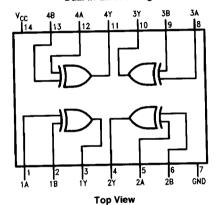
Employing complementary MOS (CMOS) transistors to achieve wide power supply operating range, low power consumption and high noise margin these gates provide basic functions used in the implementation of digital integrated circuit systems. The N- and P-channel enhancement mode transistors provide a symmetrical circuit with output swing essentially equal to the supply voltage. No DC power other than that caused by leakage current is consumed during static condition. All inputs are protected from damage due to static discharge by diode clamps to V_{CC} and GND.

Features

- Wide supply voltage range
- Guaranteed noise margin
- High noise immunity
- Low power TTL compatibility
- Low power consumption
- 3.0V to 15V 1.0V
- 0.45 V_{CC} (typ.)
 - Fan out of 2 driving 74L
- 10 nW/package (typ.)
- The MM54C86/MM74C86 follows the MM54LS86/MM74LS86 Pinout

Connection Diagram

Dual-In-Line Package



TL/F/5887-1

Order Number MM54C86* or MM74C86*

Truth Table

Inputs		Output
A	В	Y
L	L	L
L	Н	Н
н	L	н
н	Н	L

H = High Level L = Low Level

^{*}Please look into Section 8, Appendix D for availability of various package types.

Absolute Maximum Ratings

If Military/Aerospace specified devices are required, contact the National Semiconductor Sales Office/Distributors for availability and specifications.

Voltage at any Pin (Note 1) -0.3V to $V_{CC} + 0.3V$

Operating Temperature Range

MM54C86 -55°C to +125°C MM74C86 -40°C to +85°C

Storage Temperature Range -65°C to +150°C

Power Dissipation (P_D)
Dual-In-Line Package
Small Outline

700 mW 500 mW

Operating Range (V $_{\rm CC}$) 3.0V to 15V Absolute Maximum (V $_{\rm CC}$) 18V Lead Temperature (Soldering, 10 seconds) 260°C

DC Electrical Characteristics Min/max limits apply across temperature range unless otherwise noted

Symbol	Parameter	Conditions	Min	Тур	Max	Units
CMOS TO C	MOS			1 .75	····	Orace
V _{IN(1)}	Logical "1" Input Voltage	V _{CC} = 5.0V V _{CC} = 10V	3.5 8.0			V V
V _{IN(0)}	Logical "0" Input Voltage	V _{CC} = 5.0V V _{CC} = 10V			1.5	V
V _{OUT(1)}	Logical "1" Output Voltage	$V_{CC} = 5.0V, I_{O} \approx -10 \mu A$ $V_{CC} = 10V, I_{O} = -10 \mu A$	4.5 9.0		2.0	V
V _{OUT(0)}	Logical "0" Output Voltage	$V_{CC} = 5.0V, I_{O} = +10 \mu A$ $V_{CC} = 10V, I_{O} = +10 \mu A$			0.5	V
I _{IN(1)}	Logical "1" Input Current	V _{CC} = 15V, V _{IN} = 15V		0.005	1.0	μΑ
I _{IN(0)}	Logical "0" Input Current	$V_{CC} = 15V, V_{IN} = 0V$	-1.0	-0.005		<u>μ</u> Α
lcc	Supply Current	V _{CC} = 15V		0.01	15	— μA
CMOS/LPT1	L INTERFACE		<u></u>			
V _{IN(1)}	Logical "1" Input Voltage	54C, V _{CC} = 4.5V 74C, V _{CC} = 4.75V	V _{CC} -1.5 V _{CC} -1.5			V
V _{IN(0)}	Logical "0" Input Voltage	54C, V _{CC} = 4.5V 74C, V _{CC} = 4.75V	30		0.8 8.0	
V _{OUT(1)}	Logical "1" Output Voltage	54C, $V_{CC} = 4.5V$, $I_{O} = -360 \mu A$ 74C, $V_{CC} = 4.75V$, $I_{O} = -360 \mu A$	2.4 2.4			
V _{OUT(0)}	Logical "0" Output Voltage	54C, $V_{CC} = 4.5V$, $I_{O} = 360 \mu A$ 74C, $V_{CC} = 4.75V$, $I_{O} = 360 \mu A$			0.4	
UTPUT DR	VE (See 54/74C Family Charac	eteristics Data Sheet) (Short Circuit Cu	urrent)			_ <u>·</u>
SOURCE	Output Source Current (P-Channel)	$V_{CC} = 5.0V, V_{OUT} = 0V$ $T_A = 25^{\circ}C$	-1.75	-3.3		mA
ISOURCE	Output Source Current (P-Channel)	V _{CC} = 10V, V _{OUT} = 0V T _A = 25°C	-8.0	-15		mA
İsink	Output Sink Current (N-Channel)	$V_{CC} = 5.0V$, $V_{OUT} = V_{CC}$ $T_A = 25^{\circ}C$	1.75	3.6		mA
Isink	Output Sink Current (N-Channel)	$V_{CC} = 10V$, $V_{OUT} = V_{CC}$ $T_A = 25$ °C	8.0	16		mA

Note 1: "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. Except for "Operating Temperature Range" they are not meant to imply that the devices should be operated at these limits. The table of "Electrical Characteristics" provides conditions for actual device operation.

AC Electrical Characteristics* (MM54C86/MM74C86) T_A = 25°C, C_L = 50 pF, unless otherwise specified

7.0 2.000						
Symbol	Parameter	Conditions	Min	Тур	Max	Units
t _{pd}	Propagation Time to Logical	$V_{CC} = 5.0V$ $V_{CC} = 10V$		110 50	185 90	ns ns
C _{IN}	Input Capacitance	Note 2		5.0		pF
Con	Power Dissipation Capacitance	(Note 3) Per Gate		20		pF

^{*}AC Parameters are guaranteed by DC correlated testing

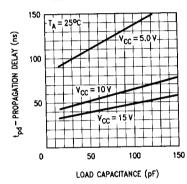
Note 1: "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. Except for "Operating Temperature Range" they are not meant to imply that the devices should be operated at these limits. The table of "Electrical Characteristics" provides conditions for actual device

Note 2: Capacitance is guaranteed by periodic testing.

Note 3: CPD determines the no load AC power consumption of any CMOS device. For complete explanation see 54C/74C Family Characteristics Application

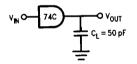
Typical Performance Characteristics

Propagation Delay Time vs Load Capacitance MM54C86/MM74C86



TL/F/5887-2

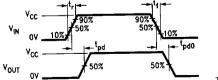
AC Test Circuit



TL/F/5887-3

Note: Delays Measured with Input t_r , $t_f = 20$ ns

Switching Time Waveforms



TL/F/5887-4